L Number	Hits	Search Text	DB	Time stamp
1	2	("5108941").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/25 14:27
2	2	("5017507").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/25 14:35
3	2	("4931411").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/25 14:37
4	2	("4855798").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/25 14:38
5	2	("5336361").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/25 14:39
6	75	RF adj sputtering and capacitor and silicon adj nitride and argon and 257/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/25 15:14
7	2	("5336361").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/25 15:40
8	2	("4855798").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/25 15:42
9	81	matrix adj display and capacitor and electrode and aluminum and sputtering and 438/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/25 16:04
10	4	("3833842").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/25 16:04
-	1191	capacitor and sputtering and silicon adj nitride and nitrogen and 438/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/25 12:35